

Data Sheet

Nonreflective, 9 kHz to 44 GHz Silicon SP4T Switch

ADRF5043

FEATURES

Ultrawideband frequency range: 9 kHz to 44 GHz Nonreflective 50 Ω design Low insertion loss 1.5 dB up to 18 GHz 2.4 dB up to 40 GHz 2.5 dB up to 44 GHz **High isolation** 44 dB up to 18 GHz 39 dB up to 40 GHz 36 dB up to 44 GHz **High input linearity** P0.1dB: 26 dBm typical IP3: 48 dBm typical **High power handling** 24 dBm through path 24 dBm terminated path All off state control Logic select control No low frequency spurs Settling time (0.1 dB final RF output): 6 µs 24-terminal, 3 mm × 3 mm LGA package Pin compatible with ADRF5042, fast switching version

APPLICATIONS

Industrial scanners Test instrumentation Cellular infrastructure—millimeterwave (mmWave) 5G Military radios, radars, electronic counter measures (ECMs) Microwave radios and very small aperture terminals (VSATs)

GENERAL DESCRIPTION

The ADRF5043 is a nonreflective, SP4T switch manufactured in the silicon on insulator (SOI) process.

The ADRF5043 operates from 9 kHz to 44 GHz with an insertion loss of lower than 2.5 dB and an isolation of higher than 36 dB. The device has a RF input power handling capability of 24 dBm for both through and terminated paths.

The ADRF5043 requires a dual-supply voltage of +3.3 V and -3.3 V. The device employs CMOS- and low voltage transistor to transistor logic (LVTTL)-compatible controls.

The ADRF5043 has enable and logic select controls to feature all off state and port mirroring, respectively.

The ADRF5043 is pin compatible with the ADRF5042 fast switching version, which operates from 100 MHz to 44 GHz.

The ADRF5043 comes in a 24-terminal, 3 mm \times 3 mm, RoHS compliant, land grid array (LGA) package and can operate from -40° C to $+105^{\circ}$ C.

Rev. A

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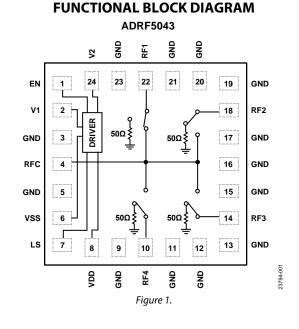


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REVISION HISTORY

2/2022—Rev. 0 to Rev. A	
Changes to Table 5 and Figure 5	6
Added Figure 6; Renumbered Sequentially	6

7/2020—Revision 0: Initial Version

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SPECIFICATIONS

Positive supply voltage (V_{DD}) = 3.3 V, negative supply voltage (V_{SS}) = -3.3 V, V1 pin voltage (V_1) = 0 V or 3.3 V, V2 pin voltage (V_2) = 0 V or 3.3 V, LS = 0 V or 3.3 V, EN = 0 V or 3.3 V, and T_{CASE} = 25°C on a 50 Ω system, unless otherwise noted. RFx refers to RF1 to RF4. V_{CTL} is the digital control inputs voltage.

Table 1.

Parameter	Symbol	Test Conditions/Comments	Min Typ	Мах	Unit
FREQUENCY RANGE	f		0.009	44,000	MHz
INSERTION LOSS					
Between RFC and RFx (On)		9 kHz to 18 GHz	1.5		dB
		18 GHz to 26 GHz	1.8		dB
		26 GHz to 35 GHz	2.1		dB
		35 GHz to 40 GHz	2.4		dB
		40 GHz to 44 GHz	2.5		dB
ISOLATION					
Between RFC and RFx (Off)		9 kHz to 18 GHz	44		dB
		18 GHz to 26 GHz	43		dB
		26 GHz to 35 GHz	40		dB
		35 GHz to 40 GHz	39		dB
		40 GHz to 44 GHz	36		dB
RETURN LOSS					
RFC and RFx (On)		9 kHz to 18 GHz	15		dB
		18 GHz to 26 GHz	15		dB
		26 GHz to 35 GHz	14		dB
		35 GHz to 40 GHz	13		dB
		40 GHz to 44 GHz	13		dB
RFx (Off)		9 kHz to 18 GHz	23		dB
		18 GHz to 26 GHz	20		dB
		26 GHz to 35 GHz	17		dB
		35 GHz to 40 GHz	15		dB
		40 GHz to 44 GHz	14		dB
SWITCHING					
Rise and Fall Time	t _{RISE} , t _{FALL}	10% to 90% of RF output	1.1		μs
On and Off Time	ton, toff	50% V _{CTL} to 90% of RF output	2.8		μs
Settling Time					
0.1 dB		50% V _{CTL} to 0.1 dB of final RF output	6		μs
0.05 dB		50% V _{CTL} to 0.05 dB of final RF output	7.8		μs
INPUT LINEARITY ¹					
0.1 dB Power Compression	P0.1dB	f = 1 MHz to 40 GHz	26		dBm
1 dB Power Compression	P1dB	f = 1 MHz to 40 GHz	27		dBm
Third-Order Intercept	IP3	Two-tone input power = 15 dBm each tone, f = 1 MHz to 40 GHz, Δ f = 1 MHz	48		dBm
Second-Order Intercept	IP2	Two-tone input power = 15 dBm each tone, f = 10 GHz, Δf = 1 MHz	120		dBm
VIDEO FEEDTHROUGH ²			3		mV p-p
SUPPLY CURRENT		VDD, VSS pins	-		
Positive Supply Current	I _{DD}		370		μA
Negative Supply Current	lss		-100		μA
DIGITAL CONTROL INPUTS		V1, V2, EN, LS pins			
Voltage		· · , ·, · , p ···· ·			
Low	VINL		0	0.8	v
High	VINE		1.2	3.3	v

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Parameter	Symbol	Test Conditions/Comments	Min	Тур	Max	Unit
Current						
Low	I _{INL}			3		μΑ
High	linh			6		μΑ
RECOMMENDED OPERATING CONDITONS						
Supply Voltage						
Positive	V _{DD}		3.15		3.45	V
Negative	V _{ss}		-3.45		-3.15	V
Digital Control Inputs Voltage	VCTL		0		V _{DD}	V
RFx Input Power ³	Pin	$f = 1 \text{ MHz to } 44 \text{ GHz}, T_{CASE} = 85^{\circ}C^{4}$				
Through Path		Average			24	dBm
		Peak			24	dBm
Terminated Path		Average			24	dBm
		Peak			24	dBm
Hot Switching		Average			24	dBm
-		Peak			24	dBm
Case Temperature	TCASE		-40		+105	°C

¹ For input linearity performance over frequency, see Figure 19 to Figure 22. ² Video feedthrough is the spurious dc transient measured at the RF ports in a 50 Ω test setup, without an RF signal present while switching the control voltage. ³ For power derating over frequency, see Figure 2. ⁴ For 105°C operation, the power handling degrades from the T_{CASE} = 85°C specification by 3 dB.

ABSOLUTE MAXIMUM RATINGS

For recommended operating conditions, see Table 1.

Table 2.

1 4010 2.							
Parameter	Rating						
Supply Voltage							
Positive	–0.3 V to +3.6 V						
Negative	–3.6 V to +0.3 V						
Digital Control Inputs ¹	-0.3 V to V _{DD} + 0.3 V or 3.3 mA, whichever occurs first						
RFx Input Power ($f^2 = 1$ MHz to 44 GHz, $T_{CASE} = 85^{\circ}C^3$)							
Through Path							
Average	26 dBm						
Peak	26dBm						
Terminated Path							
Average	25 dBm						
Peak	25dBm						
Hot Switching							
Average	25 dBm						
Peak	25dBm						
Temperature							
Junction, T	135°C						
Storage Range	–65°C to +150°C						
Reflow	260°C						

¹ Overvoltages at digital control inputs are clamped by internal diodes. Current must be limited to the maximum rating given.

² For power derating over frequency, see Figure 2.

 3 For 105°C operation, the power handling degrades from the $T_{\text{CASE}}=85^\circ\text{C}$ specification by 3 dB.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

THERMAL RESISTANCE

Thermal performance is directly linked to printed circuit board (PCB) design and operating environment. Careful attention to PCB thermal design is required.

 $\theta_{\rm JC}$ is the junction to case bottom (channel to package bottom) thermal resistance.

3. Thermal Resistance	3.	Table
3. Thermal Resistance	3.	Table

Package Type	θ」c1	Unit					
CC-24-12							
Through Path	468	°C/W					
Terminated Path	200	°C/W					

 1 θ_{JC} was determined by simulation under the following conditions: the heat transfer is due solely to thermal conduction from the channel through the ground pad to the PCB, and the ground pad is held constant at the operating temperature of 85°C.

ELECTROSTATIC DISCHARGE (ESD) RATINGS

The following ESD information is provided for handling of ESD sensitive devices in an ESD protected area only.

Human body model (HBM) per ANSI/ESDA/JEDEC JS-001.

ESD Ratings for ADRF5043

Table 4. ADRF5043, 24-Terminal LGA

ESD Model	Withstand Threshold (V)
НВМ	
RFx Pins	1000
Supply and Digital Control Pins	2000

POWER DERATING CURVES

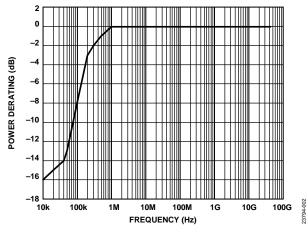


Figure 2. Power Derating vs. Frequency, Low Frequency Detail, $T_{CASE} = 85^{\circ}C$

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

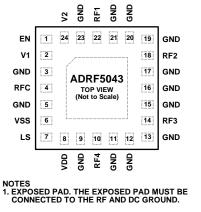


Figure 3. Pin Configuration (Top View)

23794-004

Table 5. Pin Function Descriptions

Pin No.	Mnemonic	Description
1	EN	Enable Input. This pin is internally pulled down with 100 k Ω . See Table 6 for the truth table. See Figure 6 for the interface schematic.
2	V1	Control Input 1. See Table 6 for the truth table. See Figure 5 for the interface schematic.
3, 5, 9, 11 to 13, 15 to 17, 19 to 21, 23	GND	Ground. The GND pins must be connected to the RF and dc ground of the PCB.
4	RFC	RF Common Port. RFC is dc-coupled to 0 V and ac matched to 50 Ω . No dc blocking capacitor is required when the RF line potential is equal to 0 V dc. See Figure 4 for the interface schematic.
6	VSS	Negative Supply Voltage.
7	LS	Logic Select Input. This pin is internally pulled down with 100 k Ω . See Table 6 for the truth table. See Figure 6 for the interface schematic.
8	VDD	Positive Supply Voltage.
10	RF4	RF Throw Port 4. RF4 is dc-coupled to 0 V and ac matched to 50 Ω . No dc blocking capacitor is required when the RF line potential is equal to 0 V dc. See Figure 4 for the interface schematic.
14	RF3	RF Throw Port 3. RF3 is dc-coupled to 0 V and ac matched to 50 Ω . No dc blocking capacitor is required when the RF line potential is equal to 0 V dc. See Figure 4 for the interface schematic.
18	RF2	RF Throw Port 2. RF2 is dc-coupled to 0 V and ac matched to 50 Ω . No dc blocking capacitor is required when the RF line potential is equal to 0 V dc. See Figure 4 for the interface schematic.
22	RF1	RF Throw Port 1. RF1 is dc-coupled to 0 V and ac matched to 50 Ω . No dc blocking capacitor is required when the RF line potential is equal to 0 V dc. See Figure 4 for the interface schematic.
24	V2	Control Input 2. See Table 6 for the truth table. See Figure 5 for the interface schematic.
	EPAD	Exposed Pad. The exposed pad must be connected to the RF and dc ground.

INTERFACE SCHEMATICS



Figure 4. RFC and RF1 to RF4 Interface Schematic

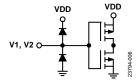


Figure 5. V1 and V2 Interface Schematic

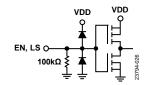
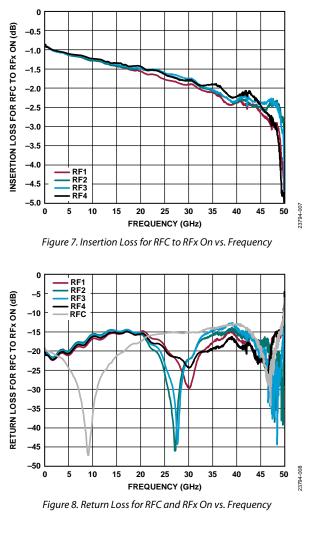


Figure 6. EN and LS Interface Schematic

TYPICAL PERFORMANCE CHARACTERISTICS

INSERTION LOSS, RETURN LOSS, AND ISOLATION

 $V_{\text{DD}} = 3.3 \text{ V}, V_{\text{SS}} = -3.3 \text{ V}, V_{\text{CTL}} = 0 \text{ V or } 3.3 \text{ V}, \text{ and } T_{\text{CASE}} = 25^{\circ}\text{C on a } 50 \Omega \text{ system, unless otherwise noted.} \text{ Measured on the evaluation board.}$



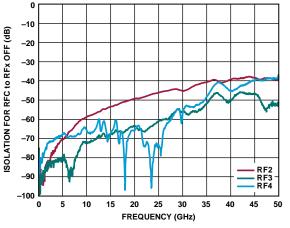


Figure 9. Isolation for RFC to RFx Off vs. Frequency, RFC to RF1 Path On

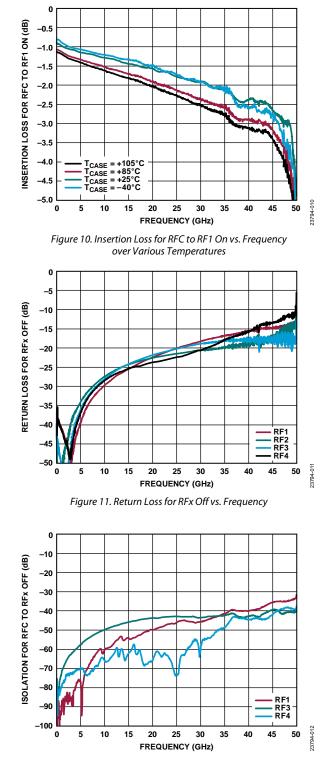


Figure 12. Isolation for RFC to RFx Off vs. Frequency, RFC to RF2 Path On

ADRF5043

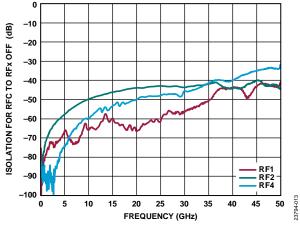


Figure 13. Isolation for RFC to RFx Off vs. Frequency, RFC to RF3 Path On

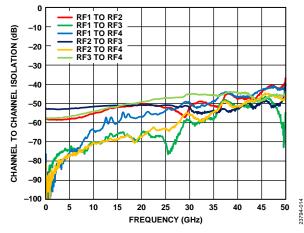


Figure 14. Channel to Channel Isolation vs. Frequency, RFC to RF1 Path On

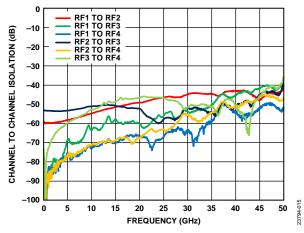


Figure 15. Channel to Channel Isolation vs. Frequency, RFC to RF3 Path On

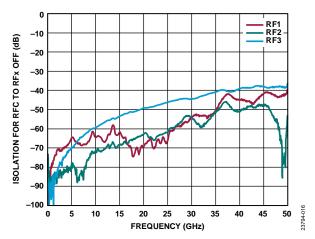


Figure 16. Isolation for RFC to RFx Off vs. Frequency, RFC to RF4 Path On

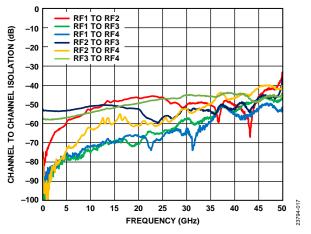


Figure 17. Channel to Channel Isolation vs. Frequency, RFC to RF2 Path On

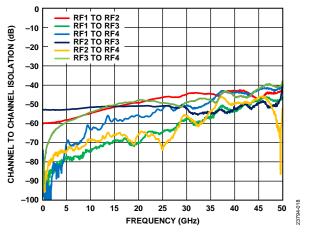


Figure 18. Channel to Channel Isolation vs. Frequency, RFC to RF4 Path On

INPUT POWER COMPRESSION AND THIRD-ORDER INTERCEPT

 V_{DD} = +3.3 V, V_{SS} = -3.3 V, V_{CTL} = 0 V or +3.3 V, and T_{CASE} = 25°C on a 50 Ω system, unless otherwise noted. Measured on the evaluation board.

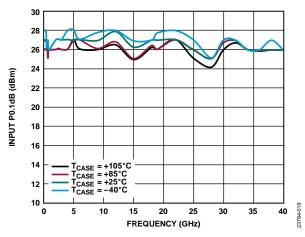


Figure 19. Input P0.1dB vs. Frequency over Various Temperatures

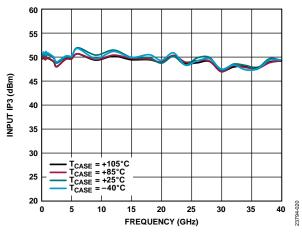


Figure 20. Input IP3 vs. Frequency over Various Temperatures

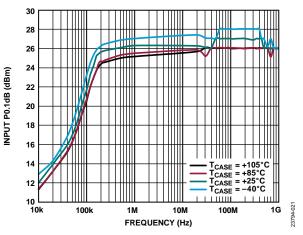
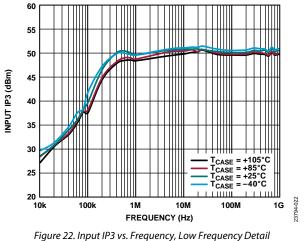


Figure 21. Input P0.1dB vs. Frequency, Low Frequency Detail over Various Temperatures



gure 22. Input IP3 vs. Frequency, Low Frequency Detai over Various Temperatures

THEORY OF OPERATION

The ADRF5043 requires a positive supply voltage applied to the VDD pin and a negative supply voltage applied to the VSS pin. Bypassing capacitors are recommended on the supply lines to minimize RF coupling.

All of the RF ports (RFC, RF1 to RF4) are dc-coupled to 0 V, and no dc blocking is required at the RF ports when the RF line potential is equal to 0 V. The RF ports are internally matched to 50 Ω . Therefore, external matching networks are not required.

The ADRF5043 integrates a driver to perform logic functions internally and to provide the user with the advantage of a simplified CMOS-/LVTTL-compatible control interface. The driver features four digital control input pins (EN, LS, V1, and V2) that control the state of the RFx paths (see Table 6).

The logic select input (LS) allows the user to define the control input logic sequence for the RF path selections. The logic level applied to the V1 and V2 pins determines which RFx port is in the insertion loss state while the other three paths are in the isolation state.

When the EN pin is logic high, all four RFx paths are in isolation state regardless of the logic state of LS, V1, V2. RFx ports are terminated to internal 50 Ω resistors, and RFC becomes reflective.

The insertion loss path conducts the RF signal between the selected RF throw port and the RF common port. The switch design is bidirectional with equal power handling capabilities. The RF input signal can be applied to the RFC port or the selected RF throw port. The isolation paths provide high loss between the insertion loss path and the unselected RF throw ports that are terminated to internal 50 Ω resistors.

The ideal power-up sequence is as follows:

- 1. Connect GND to ground.
- 2. Power up VDD and VSS. Powering up VSS after VDD avoids current transients on VDD during ramp up.
- 3. Apply a control voltage to the digital control inputs (EN, LS, V1, and V2). Applying a control voltage to the digital control inputs before the VDD supply can inadvertently forward bias and damage the internal ESD protection structures. Use a series 1 k Ω resistor to limit the current flowing into the control pin in such cases. If the control pins are not driven to a valid logic state (that is, controller output is in high impedance state) after VDD is powered up, it is recommended to use a pull-up or pull-down resistor.
- 4. Apply an RF input signal.

The ideal power-down sequence is the reverse order of the power-up sequence.

Table 6. Control Voltage Truth Table

Digital Control Inputs					RFx	Paths	
EN	LS	V1	V2	RFC to RF1	RFC to RF2	RFC to RF3	RFC to RF4
Low	Low	Low	Low	Insertion loss (on)	Isolation (off)	Isolation (off)	Isolation (off)
Low	Low	High	Low	Isolation (off)	Insertion loss (on)	Isolation (off)	Isolation (off)
Low	Low	Low	High	Isolation (off)	Isolation (off)	Insertion loss (on)	Isolation (off)
Low	Low	High	High	Isolation (off)	Isolation (off)	Isolation (off)	Insertion loss (on)
Low	High	Low	Low	Isolation (off)	Isolation (off)	Isolation (off)	Insertion loss (on)
Low	High	High	Low	Isolation (off)	Isolation (off)	Insertion loss (on)	Isolation (off)
Low	High	Low	High	Isolation (off)	Insertion loss (on)	Isolation (off)	Isolation (off)
Low	High	High	High	Insertion loss (on)	Isolation (off)	Isolation (off)	Isolation (off)
High	Low or high	Low or high	Low or high	Isolation (off)	Isolation (off)	Isolation (off)	Isolation (off)

APPLICATION INFORMATION EVALUATION BOARD

All measurements in this data sheet are measured on the ADRF5043-EVALZ evaluation board. Figure 25 shows the simplified application circuit for ADRF5043-EVALZ evaluation board. See the ADRF5043-EVALZ user guide for more information on using the evaluation board.

The design of the ADRF5043-EVALZ board serves as a layout recommendation. The Gerber files of the ADRF5043-EVALZ evaluation board are available at www.analog.com/EVAL-ADRF5043.

The ADRF5043-EVALZ is a 4-layer evaluation board. The outer copper (Cu) layers are 0.5 oz (0.7 mil) plated to 1.5 oz (2.2 mil) and are separated by dielectric materials. Figure 23 shows the cross sectional view of the evaluation board stackup.

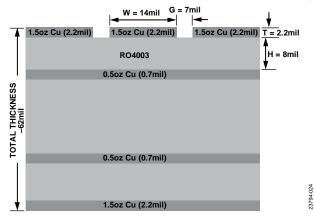


Figure 23. Evaluation Board Cross Sectional View

All RF traces are routed on the top copper layer, whereas the inner and bottom layers are grounded planes that provide a solid ground for the RF transmission lines. The top dielectric material is 8 mil Rogers RO4003, offering optimal high frequency performance. The middle and bottom dielectric materials provide mechanical strength. The total board thickness is 62 mil, which allows 2.4 mm RF launchers to be connected at the board edges.

The RF transmission lines were designed using a coplanar waveguide (CPWG) model, with a trace width of 14 mil and a ground clearance of 7 mil to have a characteristic impedance of 50 Ω . The RF transmission lines are tapered at the RFC or RFx pin transition, as shown in Figure 24. For optimal RF and thermal grounding, arrange as many plated through vias as possible around the transmission lines and under the exposed pad of the package.

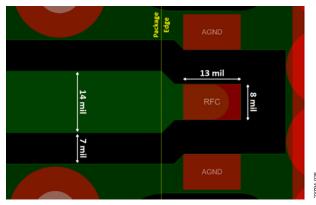
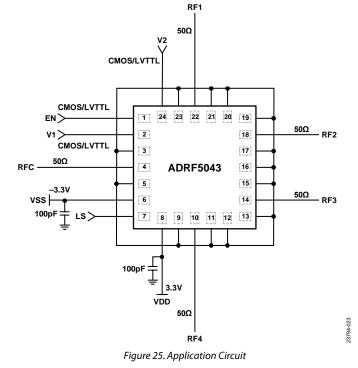
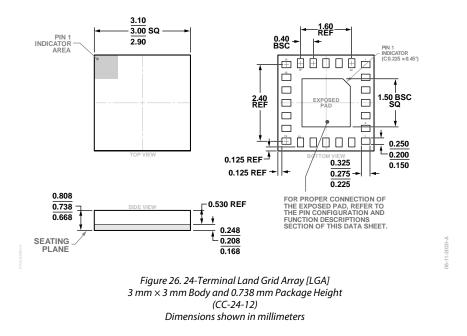


Figure 24. RF Trasmission Lines



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OUTLINE DIMENSIONS



ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Package Option	Marking Code
ADRF5043BCCZN	-40°C to +105°C	24-Terminal Land Grid Array [LGA]	CC-24-12	043
ADRF5043BCCZN-R7	-40°C to +105°C	24-Terminal Land Grid Array [LGA]	CC-24-12	043
ADRF5043-EVALZ		Evaluation Board		

¹ Z = RoHS Compliant Part.

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